

# 3.3V CMOS 12-BIT TO 24-BIT MULTIPLEXED D-TYPE LATCH WITH 3-STATE OUTPUTS AND BUS-HOLD

**IDT74ALVCHR16260**

## FEATURES:

- 0.5 MICRON CMOS Technology
- Typical  $t_{SK(0)}$  (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015;  
> 200V using machine model ( $C = 200\text{pF}$ ,  $R = 0$ )
- 0.635mm pitch SSOP, 0.50mm pitch TSSOP,  
and 0.40mm pitch TVSOP packages
- Extended commercial range of  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$
- $V_{CC} = 3.3\text{V} \pm 0.3\text{V}$ , Normal Range
- $V_{CC} = 2.7\text{V}$  to  $3.6\text{V}$ , Extended Range
- $V_{CC} = 2.5\text{V} \pm 0.2\text{V}$
- CMOS power levels ( $0.4\mu\text{W}$  typ. static)
- Rail-to-Rail output swing for increased noise margin

### Drive Features for ALVCHR16260:

- Balanced Output Drivers:  $\pm 12\text{mA}$
- Low switching noise

### APPLICATIONS:

- 3.3V High Speed Systems
- 3.3V and lower voltage computing systems

**DESCRIPTION:**

This 12-bit to 24-bit multiplexed D-type latch is built using advanced dual metal technology. The ALVCHR16260 is used in

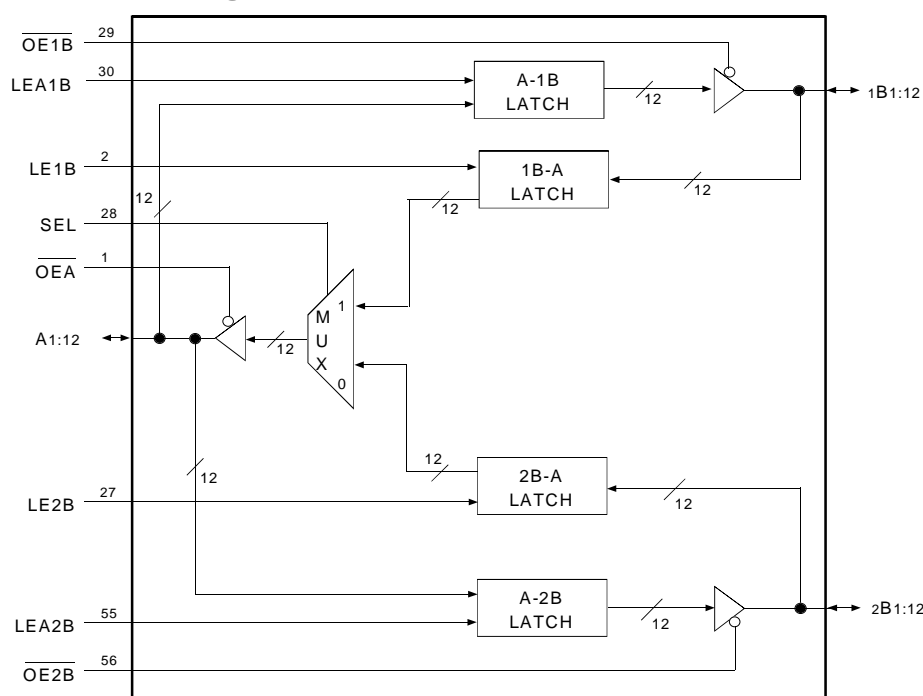
applications in which two separate data paths must be multiplexed onto, or demultiplexed from, a single data path. Typical applications include multiplexing and/or demultiplexing address and data information in microprocessor or bus-interface applications. This device also is useful in memory interleaving applications.

Three 12-bit I/O ports (A1-A12, 1B1-1B12, and 2B1-2B12) are available for address and/or data transfer. The output-enable (OE1B, OE2B, and OEA) inputs control the bus transceiver functions. The OE1B and OE2B control signals also allow bank control in the A-to-B direction. Address and/or data information can be stored using the internal storage latches. The latch-enable (LE1B, LE2B, LEA1B, and LEA2B) inputs are used to control data storage. When the latch-enable input is high, the latch is transparent. When the latch-enable input goes low, the data present at the inputs is latched and remains latched until the latch-enable input is returned high.

The ALVCHR16260 has series resistors in the device output structure which will significantly reduce line noise when used with light loads. This driver has been designed to drive  $\pm 12\text{mA}$  at the designated threshold levels.

The ALVCHR16260 has "bus-hold" which retains the inputs' last state whenever the input goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

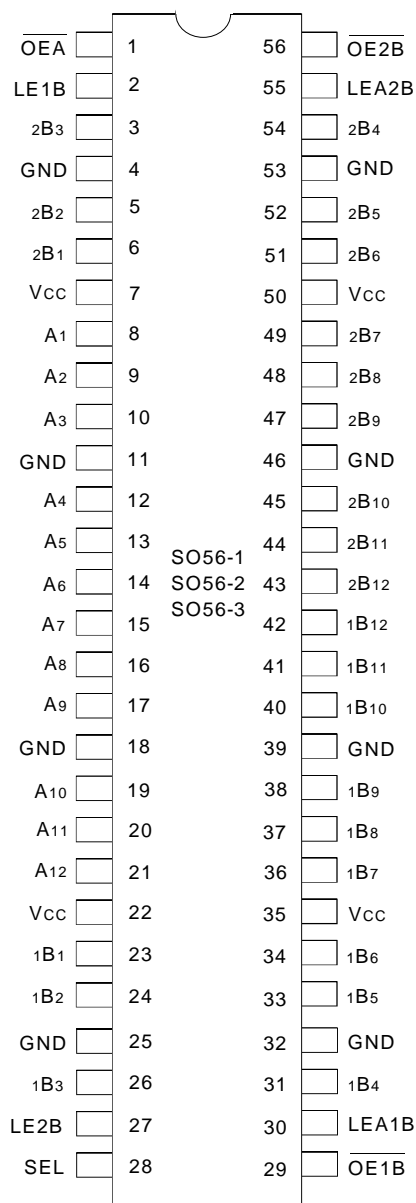
### Functional Block Diagram



## EXTENDED COMMERCIAL TEMPERATURE RANGE

**JULY 1999**

## PIN CONFIGURATION



SSOP/  
TSSOP/TVSOP  
TOP VIEW

## ABSOLUTE MAXIMUM RATING (1)

Symbol	Description	Max.	Unit
$V_{TERM}^{(2)}$	Terminal Voltage with Respect to GND	- 0.5 to + 4.6	V
$V_{TERM}^{(3)}$	Terminal Voltage with Respect to GND	- 0.5 to $V_{CC} + 0.5$	V
TSTG	Storage Temperature	- 65 to + 150	°C
I <sub>OUT</sub>	DC Output Current	- 50 to + 50	mA
I <sub>IK</sub>	Continuous Clamp Current, $V_I < 0$ or $V_I > V_{CC}$	± 50	mA
I <sub>OK</sub>	Continuous Clamp Current, $V_O < 0$	- 50	mA
I <sub>CC</sub> I <sub>SS</sub>	Continuous Current through each V <sub>CC</sub> or GND	± 100	mA

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### NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V<sub>CC</sub> terminals.
- All terminals except V<sub>CC</sub>.

## CAPACITANCE (T<sub>A</sub> = +25°C, f = 1.0MHz)

Symbol	Parameter(1)	Conditions	Typ.	Max.	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>IN</sub> = 0V	5	7	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>OUT</sub> = 0V	7	9	pF
C <sub>I/O</sub>	I/O Port Capacitance	V <sub>IN</sub> = 0V	7	9	pF

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### NOTE:

- As applicable to the device type.

## PIN DESCRIPTION

Pin Names	I/O	Description
Ax(1:12)	I/O	Bidirectional Data Port A. Usually connected to the CPU's Address/Data bus. <sup>(1)</sup>
1Bx(1:12)	I/O	Bidirectional Data Port 1B. Connected to the even path or even bank of memory. <sup>(1)</sup>
2Bx(1:12)	I/O	Bidirectional Data Port 2B. Connected to the odd path or odd bank of memory. <sup>(1)</sup>
LEA1B	I	Latch Enable Input for A-1B latch. The latch is open when LEA1B is HIGH. Data from the A port is latched on the HIGH to LOW transition of LEA1B.
LEA2B	I	Latch Enable Input for A-2B latch. The latch is open when LEA2B is HIGH. Data from the A port is latched on the HIGH to LOW transition of LEA2B.
LE1B	I	Latch Enable Input for 1B-A latch. The latch is open when LE1B is HIGH. Data from the 1B port is latched on the HIGH to LOW transition of LE1B.
LE2B	I	Latch Enable Input for 2B-A latch. The latch is open when LE2B is HIGH. Data from the 2B port is latched on the HIGH to LOW transition of LE2B.
SEL	I	1B or 2B Path Selection. When HIGH, SEL enables data transfer from 1B port to A port. When LOW, SEL enables data transfer from 2B port to A port.
OEA	I	Output Enable for A port (Active LOW)
OE1B	I	Output Enable for 1B port (Active LOW)
OE2B	I	Output Enable for 2B port (Active LOW)

### NOTE:

1. These pins have "Bus-Hold." All other pins are standard inputs, outputs, or I/Os.

## FUNCTION TABLES <sup>(1)</sup>

### B TO A ( $\overline{OEB} = H$ )

Inputs						Outputs
1Bx	2Bx	SEL	LE1B	LE2B	$\overline{OEA}$	Ax
H	X	H	H	X	L	H
L	X	H	H	X	L	L
X	X	H	L	X	L	A <sub>0</sub> <sup>(2)</sup>
X	H	L	X	H	L	H
X	L	L	X	H	L	L
X	X	L	X	L	L	A <sub>0</sub> <sup>(2)</sup>
X	X	X	X	X	H	Z

### NOTES:

1. H = HIGH Voltage Level  
L = LOW Voltage Level  
X = Don't Care  
Z = High-Impedance
2. Output level before the indicated steady-state input conditions were established.

### A TO B ( $\overline{OEB} = H$ )

Inputs					Outputs	
Ax	LEA1B	LEA2B	$\overline{OE1B}$	$\overline{OE2B}$	1Bx	2Bx
H	H	H	L	L	H	H
L	H	H	L	L	L	L
H	H	L	L	L	H	2B <sub>0</sub> <sup>(2)</sup>
L	H	L	L	L	L	2B <sub>0</sub> <sup>(2)</sup>
H	L	H	L	L	1B <sub>0</sub> <sup>(2)</sup>	H
L	L	H	L	L	1B <sub>0</sub> <sup>(2)</sup>	L
X	L	L	L	L	1B <sub>0</sub> <sup>(2)</sup>	2B <sub>0</sub> <sup>(2)</sup>
X	X	X	H	H	Z	Z
X	X	X	L	H	Active	Z
X	X	X	H	L	Z	Active
X	X	X	L	L	Active	Active

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = – 40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. <sup>(1)</sup>	Max.	Unit
VIH	Input HIGH Voltage Level	VCC = 2.3V to 2.7V		1.7	—	—	V
		VCC = 2.7V to 3.6V		2	—	—	
VIL	Input LOW Voltage Level	VCC = 2.3V to 2.7V		—	—	0.7	V
		VCC = 2.7V to 3.6V		—	—	0.8	
IiH	Input HIGH Current	VCC = 3.6V	Vi = VCC	—	—	± 5	μA
IiL	Input LOW Current	VCC = 3.6V	Vi = GND	—	—	± 5	
IozH	High Impedance Output Current (3-State Output pins)	VCC = 3.6V	Vo = VCC	—	—	± 10	μA
IozL			Vo = GND	—	—	± 10	μA
VIK	Clamp Diode Voltage	VCC = 2.3V, IIN = – 18mA		—	– 0.7	– 1.2	V
VH	Input Hysteresis	VCC = 3.3V		—	100	—	mV
ICCL	Quiescent Power Supply Current	VCC = 3.6V		—	0.1	40	μA
ICCH		VIN = GND or VCC					
ICCZ							
ΔICC	Quiescent Power Supply Current Variation	One input at VCC – 0.6V, other inputs at VCC or GND		—	—	750	μA

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### NOTE:

1. Typical values are at VCC = 3.3V, +25°C ambient.

## BUS-HOLD CHARACTERISTICS

Symbol	Parameter <sup>(1)</sup>	Test Conditions		Min.	Typ. <sup>(2)</sup>	Max.	Unit
IBHH IBHL	Bus-Hold Input Sustain Current	VCC = 3.0V	Vi = 2.0V	– 75	—	—	μA
			Vi = 0.8V	75	—	—	
IBHH IBHL	Bus-Hold Input Sustain Current	VCC = 2.3V	Vi = 1.7V	– 45	—	—	μA
			Vi = 0.7V	45	—	—	
IBHHO IBHLO	Bus-Hold Input Overdrive Current	VCC = 3.6V	Vi = 0 to 3.6V	—	—	± 500	μA

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### NOTES:

1. Pins with Bus-hold are identified in the pin description.
2. Typical values are at VCC = 3.3V, +25°C ambient.

## OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Max.	Unit
VOH	Output HIGH Voltage	VCC = 2.3V to 3.6V	IOH = - 0.1mA	VCC - 0.2	—	V
		VCC = 2.3V	IOH = - 4mA	1.9	—	
			IOH = - 6mA	1.7	—	
		VCC = 2.7V	IOH = - 4mA	2.2	—	
			IOH = - 8mA	2	—	
		VCC = 3.0V	IOH = - 6mA	2.4	—	
			IOH = - 12mA	2	—	
VOL	Output LOW Voltage	VCC = 2.3V to 3.6V	IOL = 0.1mA	—	0.2	V
		VCC = 2.3V	IOL = 4mA	—	0.4	
			IOL = 6mA	—	0.55	
		VCC = 2.7V	IOL = 4mA	—	0.4	
			IOL = 8mA	—	0.6	
		VCC = 3.0V	IOL = 6mA	—	0.55	
			IOL = 12mA	—	0.8	

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### NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate VCC range. TA = - 40°C to + 85°C.

## OPERATING CHARACTERISTICS, TA = 25°C

Symbol	Parameter	Test Conditions	VCC = 2.5V ± 0.2V	VCC = 3.3V ± 0.3V	Unit
			Typical	Typical	
CPD	Power Dissipation Capacitance Outputs enabled	CL = 0pF, f = 10Mhz	37	41	pF
CPD	Power Dissipation Capacitance Outputs disabled		4	7	pF

## SWITCHING CHARACTERISTICS<sup>(1)</sup>

Symbol	Parameter	V <sub>CC</sub> = 2.5V ± 0.2V		V <sub>CC</sub> = 2.7V		V <sub>CC</sub> = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Ax to 1Bx or Ax to 2Bx	1	5.9	—	5.8	1.2	4.9	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay 1Bx to Ax or 2Bx to Ax	1	5.9	—	5.8	1.2	4.9	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay LExB to Ax	1	6.1	—	5.9	1	5	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay LEA1B to 1Bx or LEA2B to 2Bx	1	6.1	—	5.9	1	5	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay SEL to Ax	1	7.4	—	7.1	1.1	6.1	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time OEA to Ax, OE1B to 1Bx, or OE2B to 2Bx	1	7.2	—	7.1	1	6	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time OEA to Ax, OE1B to 1Bx, or OE2B to 2Bx	1	6.2	—	5.5	1.3	5.1	ns
t <sub>SU</sub>	Setup Time, data before LE1B, LE2B, LEA1B, LEA2B	1.4	—	1.1	—	1.1	—	ns
t <sub>H</sub>	Hold Time, data after LE1B, LE2B, LEA1B, LEA2B	1.6	—	1.9	—	1.5	—	ns
t <sub>W</sub>	Pulse Width, LE1B, LE2B, LEA1B, or LEA2B HIGH	3.3	—	3.3	—	3.3	—	ns
t <sub>SK(0)</sub>	Output Skew <sup>(2)</sup>	—	—	—	—	—	500	ps

### NOTES:

1. See test circuits and waveforms. T<sub>A</sub> = – 40°C to + 85°C.
2. Skew between any two outputs of the same package and switching in the same direction.

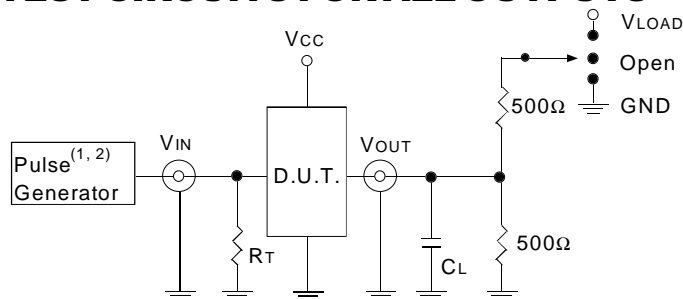
## TEST CIRCUITS AND WAVEFORMS

### TEST CONDITIONS

Symbol	V <sub>CC</sub> (1)= 3.3V±0.3V	V <sub>CC</sub> (1)= 2.7V	V <sub>CC</sub> (2)= 2.5V±0.2V	Unit
V <sub>LOAD</sub>	6	6	2 x V <sub>CC</sub>	V
V <sub>IH</sub>	2.7	2.7	V <sub>CC</sub>	V
V <sub>T</sub>	1.5	1.5	V <sub>CC</sub> / 2	V
V <sub>LZ</sub>	300	300	150	mV
V <sub>HZ</sub>	300	300	150	mV
C <sub>L</sub>	50	50	30	pF

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### TEST CIRCUITS FOR ALL OUTPUTS



#### DEFINITIONS:

C<sub>L</sub>= Load capacitance: includes jig and probe capacitance.

R<sub>T</sub>= Termination resistance: should be equal to Z<sub>OUT</sub> of the Pulse Generator.

#### NOTES:

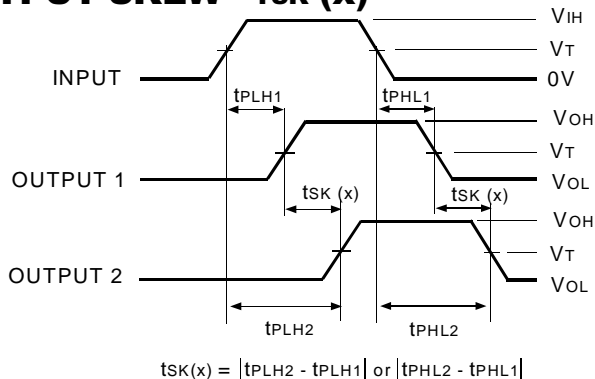
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t<sub>F</sub> ≤ 2.5ns; t<sub>R</sub> ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t<sub>F</sub> ≤ 2ns; t<sub>R</sub> ≤ 2ns.

### SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	V <sub>LOAD</sub>
Disable High Enable High	GND
All Other tests	Open

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### OUTPUT SKEW - t<sub>SK</sub> (x)



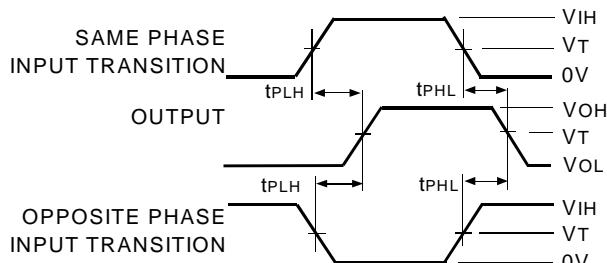
$$t_{SK}(x) = |t_{PLH2} - t_{PLH1}| \text{ or } |t_{PHL2} - t_{PHL1}|$$

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#### NOTES:

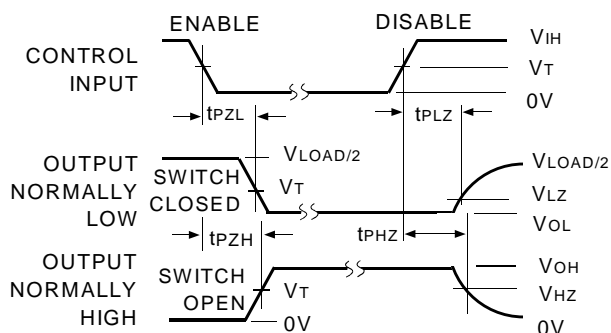
1. For t<sub>SK</sub>(o) OUTPUT1 and OUTPUT2 are any two outputs.
2. For t<sub>SK</sub>(b) OUTPUT1 and OUTPUT2 are in the same bank.

### PROPAGATION DELAY



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### ENABLE AND DISABLE TIMES

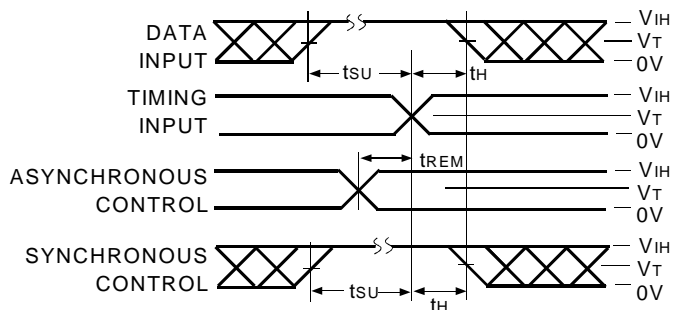


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#### NOTE:

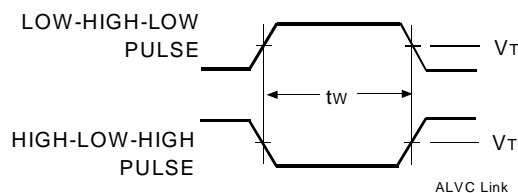
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

### SET-UP, HOLD, AND RELEASE TIMES



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### PULSE WIDTH



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## ORDERING INFORMATION

IDT	XX	ALVC	X	XX	XXX	XX	
Temp. Range	Bus-Hold	Family	Device Type	Package			
					PV	Shrink Small Outline Package (SO56-1)	
					PA	Thin Shrink Small Outline Package (SO56-2)	
					PF	Thin Very Small Outline Package (SO56-3)	
				260		12-Bit to 24-Bit Multiplexed D-Type Latch with 3-State Outputs	
				R16		Double-Density with Resistors, $\pm 12\text{mA}$	
				H		Bus-Hold	
				74		$-40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	



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